HIGH-SPEED UNIPOLAR DETECTION TYPE S-5713A Series

The S-5713A Series, developed by CMOS technology, is a unipolar detection type Hall IC with high-speed detection. The output voltage changes when the S-5713A Series detects the intensity level of flux density and a polarity. Using the S-5713A Series with a magnet makes it possible to detect opening/closing and rotation in various devices. High-density mounting is possible by using the small SOT-23-3 package.

Features

- Built-in chopping stabilized amplifier
- Detection of unipolar magnetic fields
- Applicable in various devices with wide range of option

Pole detection : Detection of S pole or N pole

-40°C to +85°C

SOT-23-3

Operating cycle 132 µs typ., 240 µs max.

Small dependency magnetic characteristics against temperature

Detection logic for magnetism : Active "L", active "H"

Output form : Nch open drain output, CMOS output

- High-speed detection :
- Operating temperature range :

• Small package :

Lead-free product

Applications

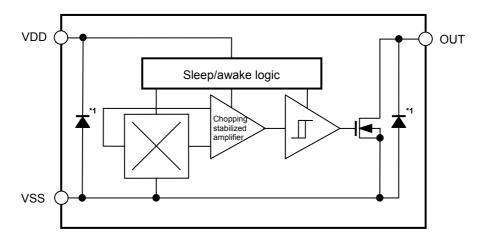
- Playthings, portable games
- Home appliances

Package

Baakaga Nama	Drawing Code					
Package Name	Package	Таре	Reel			
SOT-23-3	MP003-C	MP003-C	MP003-Z			

Block Diagrams

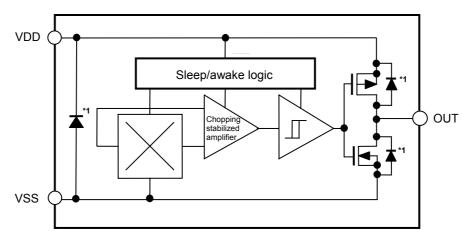
1. Nch open drain output product



*1. Parasitic diode

Figure 1

2. CMOS output product

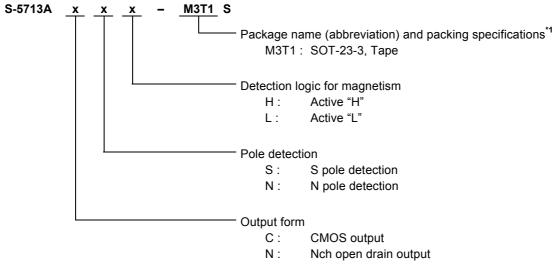


*1. Parasitic diode

Figure 2

Product Name Structure

1. Product name



*1. Refer to the tape specifications at the end of this book.

2. Product name list

Table 1

Output Form	Pole Detection	Detection Logic for Magnetism	Product Name
Nch open drain output	S pole detection	Active "L"	S-5713ANSL-M3T1S

Remark Please contact our sales office for products other than the above.

Pin Configuration

SOT-23-3 Top view

Pin No.	Symbol	Pin Description
1	VSS	GND pin
2	VDD	Power supply pin
3	OUT	Output pin

Table 2

Figure 3

Absolute Maximum Ratings

Table 3

			(Ta = 25°C unless other	wise specified)
Item		Symbol	Absolute Maximum Rating	Unit
Power su	oply voltage	V _{DD}	$V_{\rm SS}$ – 0.3 to $V_{\rm SS}$ + 7.0	V
Output	Nch open drain output		$V_{\rm SS}$ – 0.3 to $V_{\rm SS}$ + 7.0	V
voltage	CMOS output	V OUT	$V_{\text{SS}}-0.3$ to V_{DD} + 0.3	V
Power dissipation		PD	430 ^{*1}	mW
Operating ambient temperature		T _{opr}	–40 to +85	°C
Storage temperature		T _{stg}	-40 to +125	°C

*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm \times 76.2 mm \times t1.6 mm

(2) Name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

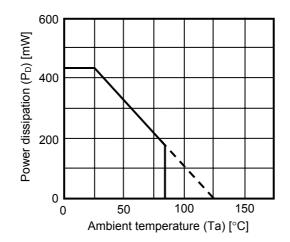


Figure 4 Power Dissipation of Package (When Mounted on Board)

Electrical Characteristics

		(Ta = 25°C, V _{DD} = 5.0 V	, V _{SS} = 0	V unles	s otherw	vise spe	ecified)
Item	Symbol	Conditions	Min.	Тур.	Max.	Unit	Test Circuit
Power supply voltage	V_{DD}	_	4.5	5.0	5.5	V	-
Average current consumption	I _{DD}	Average value	Ι	1750	2200	μA	1
Output current		Output transistor Nch, V _{OUT} = 0.4 V	1	-	_	mA	2
	I _{OUT}	CMOS output Output transistor Pch, V_{OUT} = V_{DD} – 0.4 V	Ι	_	-1	mA	2
Output leakage current	I _{LEAK}	Nch open drain output Output transistor Nch, V _{OUT} = 5.5 V	-	-	1	μA	2
Awake mode time	t _{AW}	_	-	121	-	μs	-
Sleep mode time	t _{SL}	_	_	11	_	μs	-
Operating cycle	t _{CYCLE}	t _{AW} + t _{SL}	_	132	240	μs	-

Table 4

Magnetic Characteristics

1. Product with detection of S pole

Table 5

			(Ta = 25°C, 1	V _{DD} = 5.0 \	/, V _{SS} = 0 \	/ unless ot	herwise sp	pecified)
Item		Symbol	Conditions	Min.	Тур.	Max.	Unit	Test Circuit
Operating point *1	S pole	B _{OPS}	-	_	6.1	9.1	mT	3
Release point *2	S pole	B _{RPS}	-	2.4	4.9	_	mT	3
Hysteresis width *3	S pole	B _{HYSS}	B _{HYSS} = B _{OPS} – B _{RPS}	-	1.2	_	mT	3

2. Product with detection of N pole

Table 6

(Ta = 25°C, V_{DD} = 5.0 V, V_{SS} = 0 V unless otherwise specified)

ltem		Symbol	Conditions	Min.	Тур.	Max.	Unit	Test Circuit
Operating point *1	N pole	B _{OPN}	-	-9.1	-6.1	_	mT	3
Release point *2	N pole	B _{RPN}	-	-	-4.9	-2.4	mT	3
Hysteresis width *3	N pole	B _{HYSN}	B _{HYSN} = B _{OPN} – B _{RPN}	-	1.2	-	mT	3

***1.** B_{OPN}, B_{OPS} : Operating points

The operating points are the values of magnetic flux density when the output voltage (V_{OUT}) is inverted after the magnetic flux density applied to the S-5713A Series by the magnet (N or S pole) is increased (the magnet is moved closer).

Even when the magnetic flux density exceeds B_{OPN} or $B_{\text{OPS}},\,V_{\text{OUT}}$ retains the status.

*2. B_{RPN}, B_{RPS} : Release points

The release points are the values of magnetic flux density when the output voltage (V_{OUT}) is inverted after the magnetic flux density applied to the S-5713A Series by the magnet (N or S pole) is decreased (the magnet is moved further away).

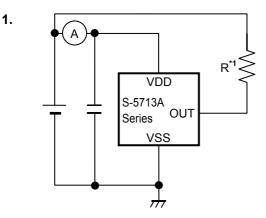
Even when the magnetic flux density is lowered than B_{RPN} or B_{RPS}, V_{OUT} retains the status.

*3. B_{HYSN}, B_{HYSS} : Hysteresis widths

B_{HYSN} and B_{HYSS} are the differences between B_{OPN} and B_{RPN}, and B_{OPS} and B_{RPS}, respectively.

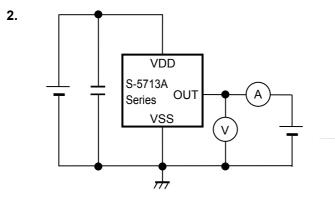
Remark The unit of magnetic density mT can be converted by using the formula 1 mT = 10 Gauss.

Test Circuits

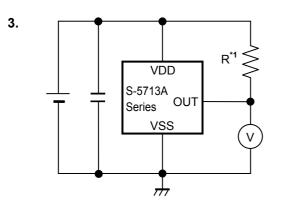


 $\ensuremath{^{\textbf{*1.}}}$ Resistor (R) is unnecessary for the CMOS output product.

Figure 5



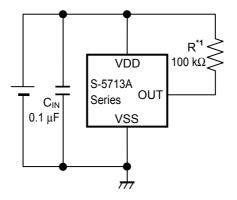




*1. Resistor (R) is unnecessary for the CMOS output product.

Figure 7

Standard Circuit



***1.** Resistor (R) is unnecessary for the CMOS output product.

Figure 8

Caution The above connection diagram and constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.

Operation

1. Direction of applied magnetic flux and position of Hall sensor

The S-5713A Series detects the flux density which is vertical to the marking surface. **Figure 9** shows the direction in which magnetic flux is being applied.

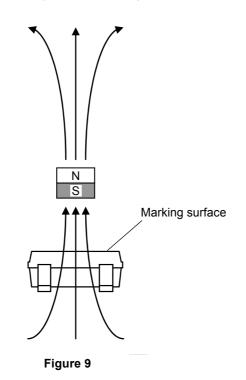


Figure 10 shows the position of Hall sensor.

The center of this Hall sensor is located in the area indicated by a circle, which is in the center of a package as described below.

The following also shows the distance (typ. value) between the marking surface and the chip surface of a package.

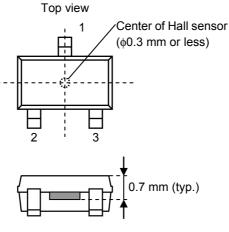


Figure 10

2. Basic operation

The S-5713A Series changes the output voltage (V_{OUT}) according to the level of the magnetic flux density (N or S pole) applied by a magnet.

The following explains the operation when the magnetism detection logic is active "L".

(1) Products with detection of S pole

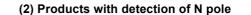
When the magnetic flux density vertical to the marking surface exceeds B_{OPS} after the S pole of a magnet is moved closer to the marking surface of the S-5713A Series, V_{OUT} changes from "H" to "L". When the S pole of a magnet is moved further away from the marking surface of the S-5713A Series and the magnetic flux density is lower than B_{RPS} , V_{OUT} changes from "L" to "H".

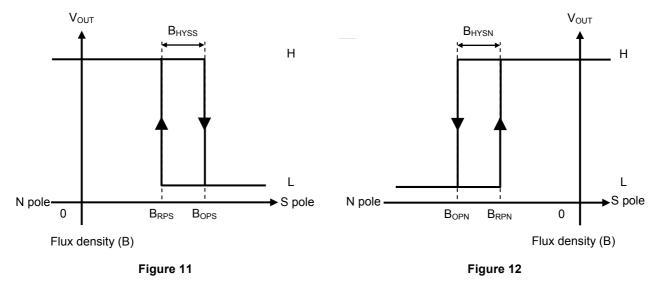
(2) Products with detection of N pole

When the magnetic flux density vertical to the marking surface exceeds B_{OPN} after the N pole of a magnet is moved closer to the marking surface of the S-5713A Series, V_{OUT} changes from "H" to "L". When the N pole of a magnet is moved further away from the marking surface of the S-5713A Series and the magnetic flux density is lower than B_{RPN} , V_{OUT} changes from "L" to "H".

Figures 11 to 12 show the relationship between the magnetic flux density and V_{OUT} .

(1) Products with detection of S pole

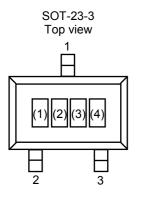




Precautions

- If the impedance of the power supply is high, the IC may malfunction due to a supply voltage drop caused by through-type current. Take care with the pattern wiring to ensure that the impedance of the power supply is low.
- Note that the IC may malfunction if the power supply voltage rapidly changes.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- Large stress on this IC may affect on the magnetic characteristics. Avoid large stress which is caused by bend and distortion during mounting the IC on a board or handle after mounting.
- When designing for mass production using an application circuit described herein, the product deviation and temperature characteristics of the external parts should be taken into consideration. SII shall not bear any responsibility for patent infringements related to products using the circuits described herein.
- SII claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

Marking Specifications

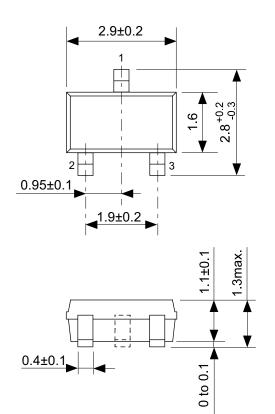


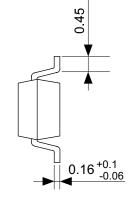
(1) to (3): Product code (Refer to **Product name vs. Product code**.)
(4): Lot number

Product name vs. Product code

Product Name	Product Code			
Floduct Maille	(1)	(2)	(3)	
S-5713ANSL-M3T1S	Т	2	D	

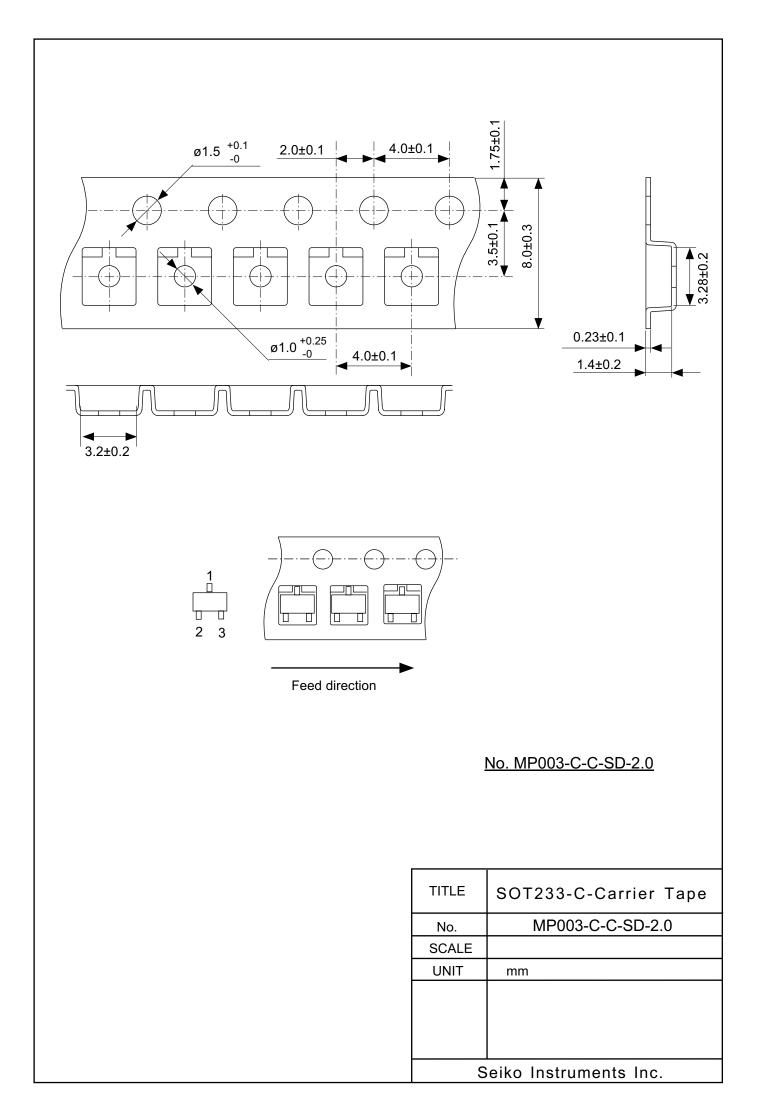
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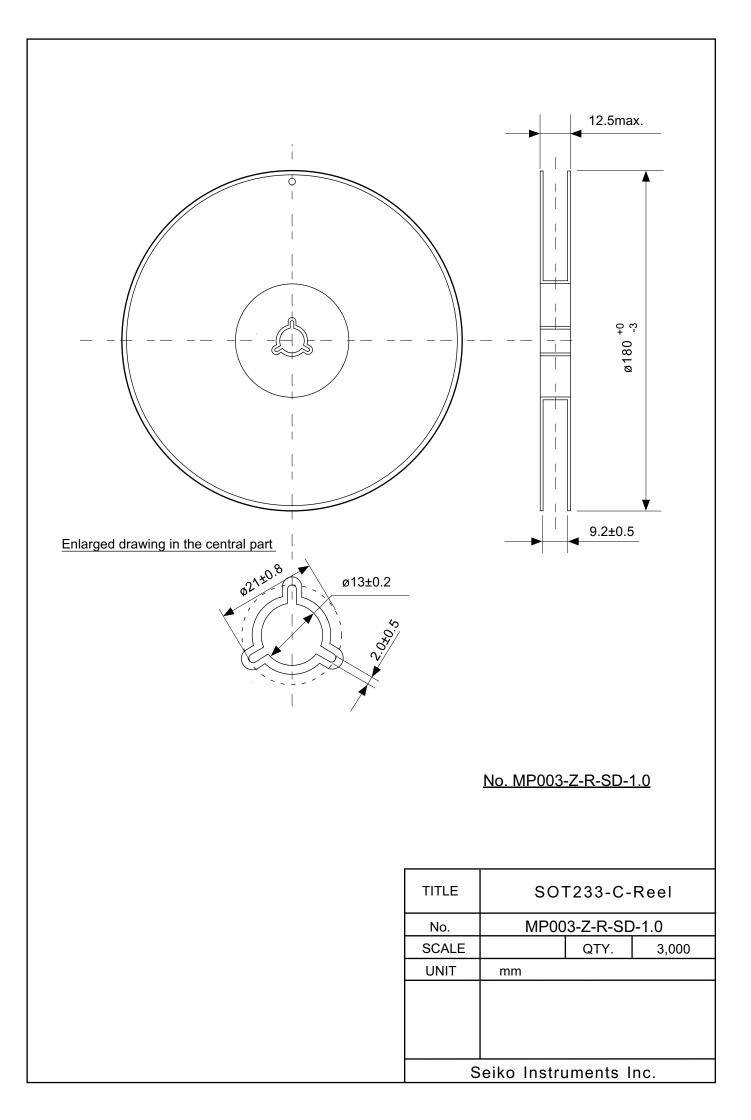




No. MP003-C-P-SD-1.0

TITLE	SOT233-C-PKG Dimensions			
No.	MP003-C-P-SD-1.0			
SCALE				
UNIT	mm			
Seiko Instruments Inc.				





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